



(19)  
(12)

(KR)  
(B1)

(45)  
(11)  
(24)

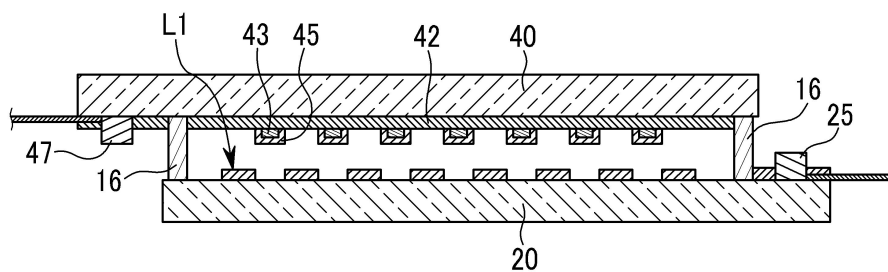
2010 04 20  
10-0953655  
2010 04 12

(51)	Int. Cl.	(73)	
	<i>HD5B 33/02</i> (2006 01) <i>HD5B 33/22</i> (2006 01)		24
	<i>HD1L 51/50</i> (2006 01)		
(21)	10-2008-0066079	(72)	
(22)	2008 07 08		
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(65)	10-2010-0005952	201 1502	
(43)	2010 01 18	(74)	
(56)	JP2008091037 A KR100762682 B1 KR1020050002606 A KR1020070083352 A		
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(54)

(57)

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MHL(Metal Insulator Hybrid Layer),

(black polymer),

(carbon black)

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ITO(Indium Tin Oxide), IZO(Indium Zinc Oxide), AZO(Aluminum doped Zinc Oxide),  
GZO(Gallium doped Zinc Oxide), FTO(Fluorine Tin Oxide), ATO(Antimony doped Tin Oxide)

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1 ;  
1 2 ;  
2 ;  
, 2  
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13

12 ,

14

12 ,

15

12 ,

[0001]

[0002]

(exciton)

[0003]

[0004]

(touch screen)

Interface), GUI (Graphical User Interface), PDA,

[0006]

( )

[0007]

[0008]

[0009]

 $[0010]$ 

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 $[001\ 1]$ 

ML (Metal Insulator Layer), (black polymer),  
(carbon black).

[0012]

[0013]

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ITO(Indium Tin Oxide), IZO(Indium Zinc Oxide), AZO(Aluminum doped Zinc Oxide), GZO(Gallium doped Zinc Oxide), FTO(Fluorine Tin Oxide), ATO(Antimony-doped Tin Oxide).

[0014]

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[0015]

- [0016] ,
- [0017] ,
- [0018] ,
- [0019] 1
- [0020] 1 , 1 (20) , 1 (20)  
(L1) , (16) 1 (20) 2 (40) , 2 (40)  
(43)
- [0021] 1 (20) (L1) , (L1)  
(chip on glass; COG) (25)
- [0022] 2 (40) (42) (42) (43) , (43)  
(45) (42) (43) (45) 2 (40) , 1  
(20) 2 (40)
- [0023] 2 (40) (45) (43) ,  
(45) (43) 1 (20)
- [0024] 1 (20) 2 (40) ,  
, 1 (20) 2 (40) ( )
- [0025] (42) ITO(Indium Tin Oxide), IZO(Indium Zinc Oxide), AZO(Aluminum doped Zinc Oxide), GZO(Gallium doped Zinc Oxide), FTO(Fluorine Tin Oxide), ATO(Antimony doped Tin Oxide)  
(43)  
, (L1) (L1)
- [0026] 2 (45) (43) , (L1)  
(43) (43) 1 (20)  
(43) 2 (40) (45) 2  
(40)
- [0027] (45)  
, MHL(Metal Insulator Hybrid Layer), (black polymer), (carbon black)  
, MHL SiO<sub>2</sub> SiN<sub>x</sub>  
, Cr, Al, Mo, W, Ti, Ag, Cu
- [0028] (45) ,
- [0029] 2 (40) (43) (43)  
(47)
- [0030] 3 1 , 4 1
- [0031] 3 4 , (L1)  
(L1) (26) (28) (30) , 2

(T1, T2) (C1)  
(T1) (T2)

[0032]

(T1) (SL1) (DL1) (SL1) (C1)  
(DL1) (T2)  
(T1) (VD) (T1)  
(VD)

[0033]

(T2) (VD) (C1) (C1) (L1)  
(I<sub>QED</sub>) (L1)  
(I<sub>QED</sub>) (T2) (32) (34) (36)  
(L1) (26) (T2) (34)

[0034]

2 (40) (43) 2 (40)  
(43) (43) (45) (45)

[0035]

(45) (43)

[0036]

(43)  
5 2 (45) (48) 5 (48)  
(R), (G), (B)  
(45) (48)

[0037]

[0038]

1 1

[0039]

2 1 1

[0040]

3 1

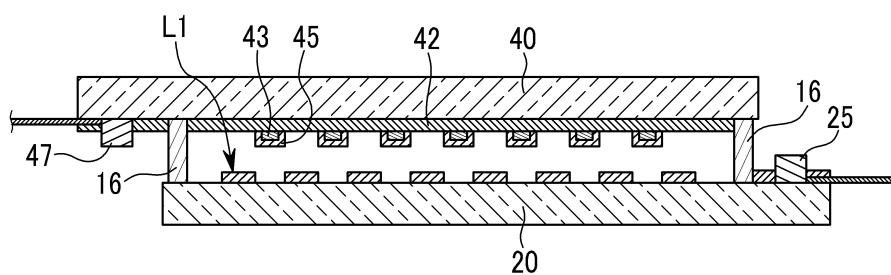
[0041]

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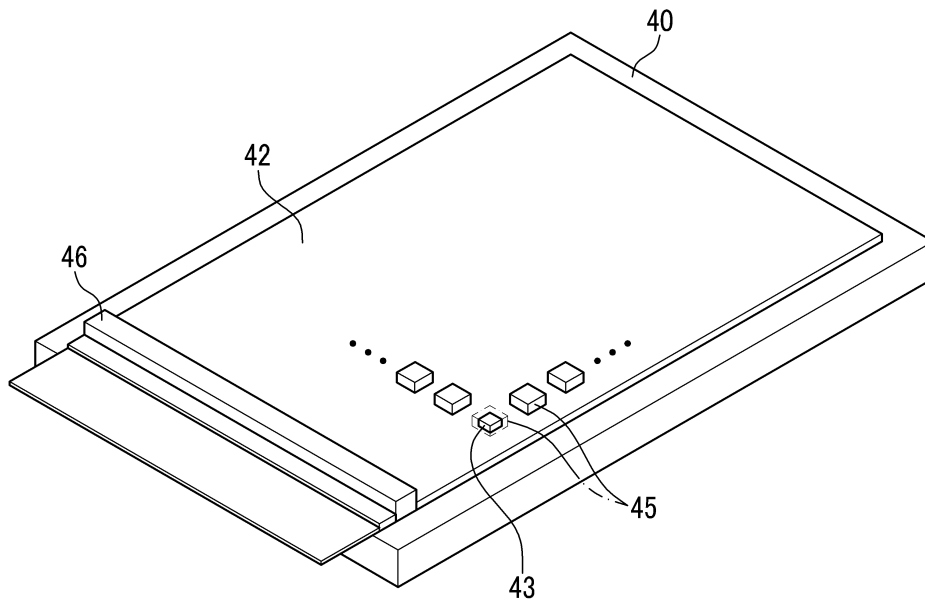
[0042]

5 2

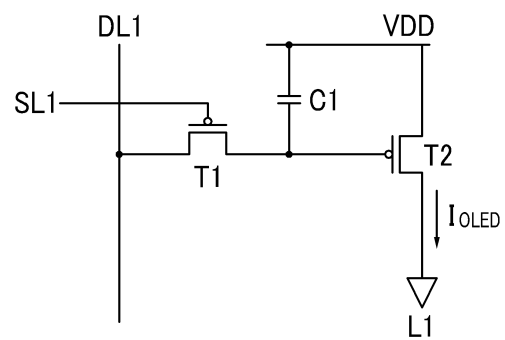
1



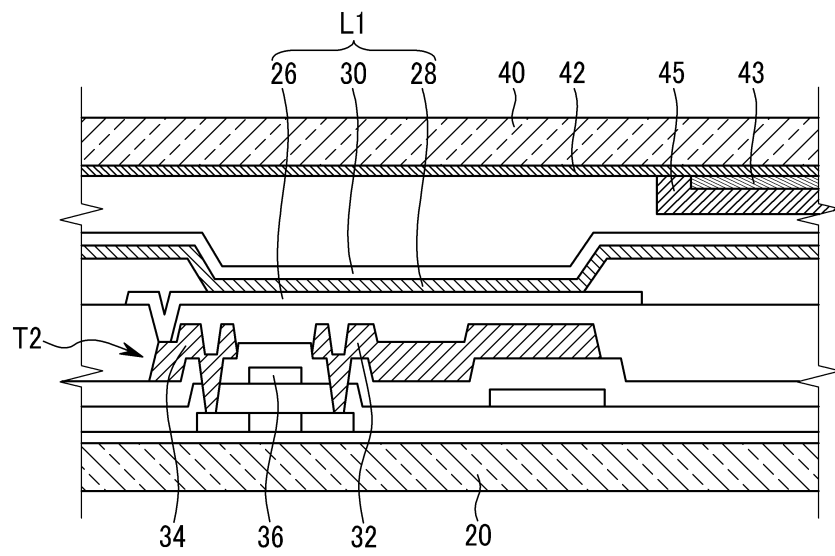
2



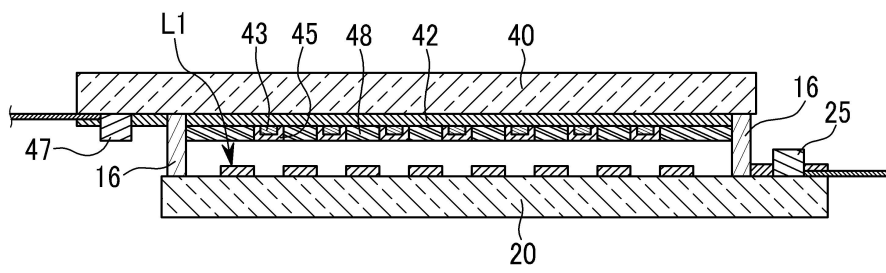
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专利名称(译)	有机发光显示器		
公开(公告)号	<a href="#">KR1020100005952A</a>	公开(公告)日	2010-01-18
申请号	KR1020080066079	申请日	2008-07-08
[标]申请(专利权)人(译)	三星显示有限公司		
申请(专利权)人(译)	三圣母工作显示有限公司		
当前申请(专利权)人(译)	三圣母工作显示有限公司		
[标]发明人	KIM EUN AH		
发明人	KIM, EUN AH		
IPC分类号	H01L51/50 H05B33/02 H05B33/22		
CPC分类号	H01L27/14678 H01L27/3272 H01L27/3227 H01L27/3244 H01L27/323 H01L27/322		
其他公开文献	KR100953655B1		
外部链接	<a href="#">Espacenet</a>		

## 摘要(译)

根据本发明的有机发光显示装置包括光电传感器，其捕获结合到第一基板的第二基板的变化，其中形成有机发光装置和第一基板，以及由外部源产生的入射光它形成在第二基板和它阻挡的阻挡层中，使得光电传感器能够在覆盖光电传感器的同时不能感测从有机发光装置发光的光。有机电致发光，触摸屏，薄膜晶体管，光电传感器，阻挡层，黑色矩阵。

